TOSHIBA Field Effect Transistor Silicon N Channel MOS Type

# SSM3K119TU

Power Management Switch Applications High Speed Switching Applications

• 1.8 V drive

• Low ON-resistance:  $R_{on} = 134 \text{ m}\Omega \text{ (max) (@V_{GS} = 1.8V)}$ 

 $R_{on} = 90 \text{ m}\Omega \text{ (max) (@V_{GS} = 2.5V)}$  $R_{on} = 74 \text{ m}\Omega \text{ (max) (@V_{GS} = 4.0V)}$ 

#### Absolute Maximum Ratings (Ta = 25°C)

Characteristi	С	Symbol	Rating	Unit	
Drain-source voltage		V <sub>DS</sub>	30	V	
Gate-source voltage		V <sub>GSS</sub>	± 12	V	
Drain current	DC	I <sub>D</sub>	2.5	$\Delta$ (	
	Pulse	I <sub>DP</sub>	5.0		
Drain power dissipation		P <sub>D</sub> (Note 1)	800	(mw\	
Drain power dissipation		P <sub>D</sub> (Note 2)	500		
Channel temperature		T <sub>ch</sub>	150	°C	
Storage temperature ran	ge	T <sub>stg</sub>	-55 to 150	°C	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba

Semiconductor Reliability Handbook ("Handling Precautions") Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Mounted on a ceramic board.

 $(25.4 \text{ mm} \times 25.4 \text{ mm} \times 0.8 \text{ t}, \text{ Cu Pad: } 645 \text{ mm}^2)$ 

Note 2: Mounted on an FR4 board.

 $(25.4 \text{ mm} \times 25.4 \text{ mm} \times 1.6 \text{ t}, \text{ Cu Pad: } 645 \text{ mm}^2)$ 

# 2.1±0.1 1.7±0.1 1.7±0.1 1. Gate 2. Source 3. Drain UFM JEDEC JEITA TOSHIBA 2-2U1A

Weight: 6.6 mg (typ.)

### Electrical Characteristics (Ta = 25°C)

Charact	eristic	Symbol	Test Condition		Min	Тур.	Max	Unit
Drain-source breakdown voltage		V (BR) DSS	$I_D = 1 \text{ mA}, V_{GS} = 0$		30	_	_	V
		V (BR) DSX	$I_D = 1 \text{ mA}, V_{GS} = -12 \text{ V}$		18	_	_	V
Drain cutoff current	, / 2	I <sub>DSS</sub>	$V_{DS} = 30 \text{ V}, V_{GS} = 0$		_	_	1	μА
Gate leakage curre	nt	IGSS	$V_{GS} = \pm 12 \text{ V}, V_{DS} = 0$		_	_	±1	μА
Gate threshold volt	age	V <sub>th</sub>	$V_{DS} = 3 \text{ V}, I_D = 1 \text{ mA}$		0.4	_	1.0	V
Forward transfer ac	dmittance	Yfs	V <sub>DS</sub> = 3 V, I <sub>D</sub> = 2 A	(Note3)	3.8	7.7	_	S
Drain-source ON-resistance		,(())	I <sub>D</sub> = 2.0 A, V <sub>GS</sub> = 4.0 V	(Note3)	_	55	74	
		R <sub>DS</sub> (ON)	I <sub>D</sub> = 1.0 A, V <sub>GS</sub> = 2.5 V	(Note3)	_	67	90	mΩ
			I <sub>D</sub> = 0.5 A, V <sub>GS</sub> = 1.8 V	(Note3)	_	84	134	
Input capacitance		C <sub>iss</sub>	$V_{DS} = 10 \text{ V}, V_{GS} = 0, f = 1 \text{ MHz}$		_	270		pF
Output capacitance		Coss	V <sub>DS</sub> = 10 V, V <sub>GS</sub> = 0, f = 1 MHz		_	56	_	pF
Reverse transfer capacitance		C <sub>rss</sub>	V <sub>DS</sub> = 10 V, V <sub>GS</sub> = 0, f = 1 MHz		_	47	_	pF
Switching time	Turn-on time	t <sub>on</sub>	$V_{DD} = 10 \text{ V}, I_D = 2 \text{ A},$ $V_{GS} = 0 \text{ to } 2.5 \text{ V}, R_G = 4.7 \Omega$		_	20	_	ns
	Turn-off time	t <sub>off</sub>			_	31	_	
Drain-source forward voltage		V <sub>DSF</sub>	$I_D = -2.5 \text{ A}, V_{GS} = 0 \text{ V}$	(Note3)	_	- 0.85	- 1.2	٧

Note3: Pulse test

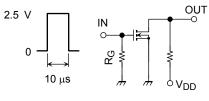
Start of commercial production 2006-03

#### **Switching Time Test Circuit**

#### (a) Test Circuit

#### (b) V<sub>IN</sub>

(c) Vout



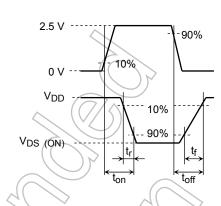
 $V_{DD} = 10 \text{ V}$ 

 $R_G = 4.7 \Omega$ Duty ≤ 1%

 $V_{IN}\text{: }t_{r}\text{, }t_{f}<5\text{ ns}$ 

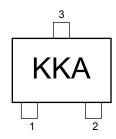
Common Source

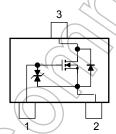
 $Ta = 25^{\circ}C$ 



#### Marking

## **Equivalent Circuit (top view)**





#### **Notice on Usage**

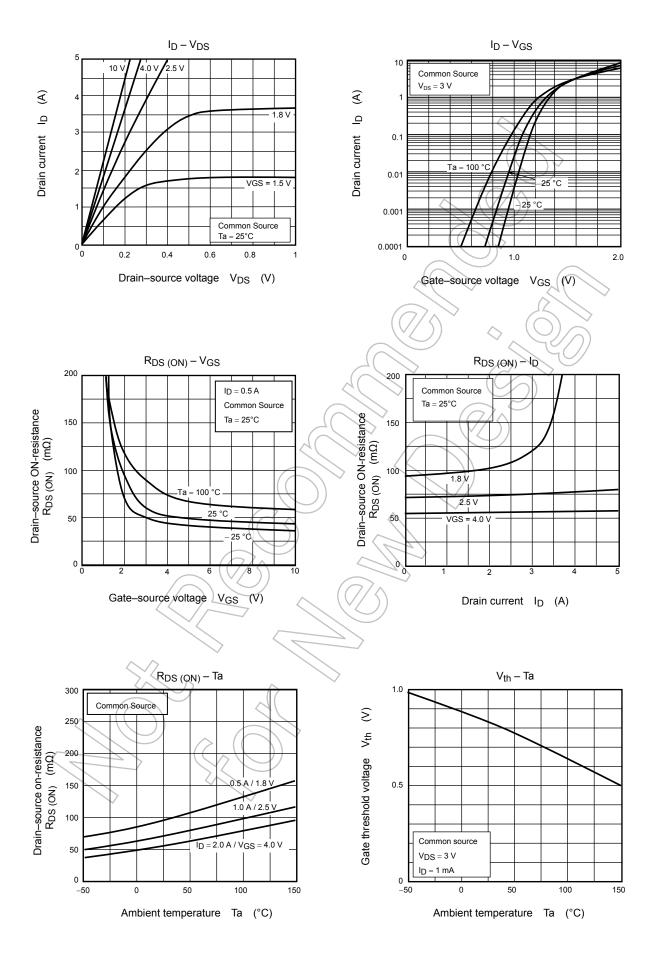
Vth can be expressed as the voltage between gate and source when the low operating current value is ID = 1 mA for this product. For normal switching operation, VGS (on) requires a higher voltage than Vth and VGS (off) requires a lower voltage than Vth.

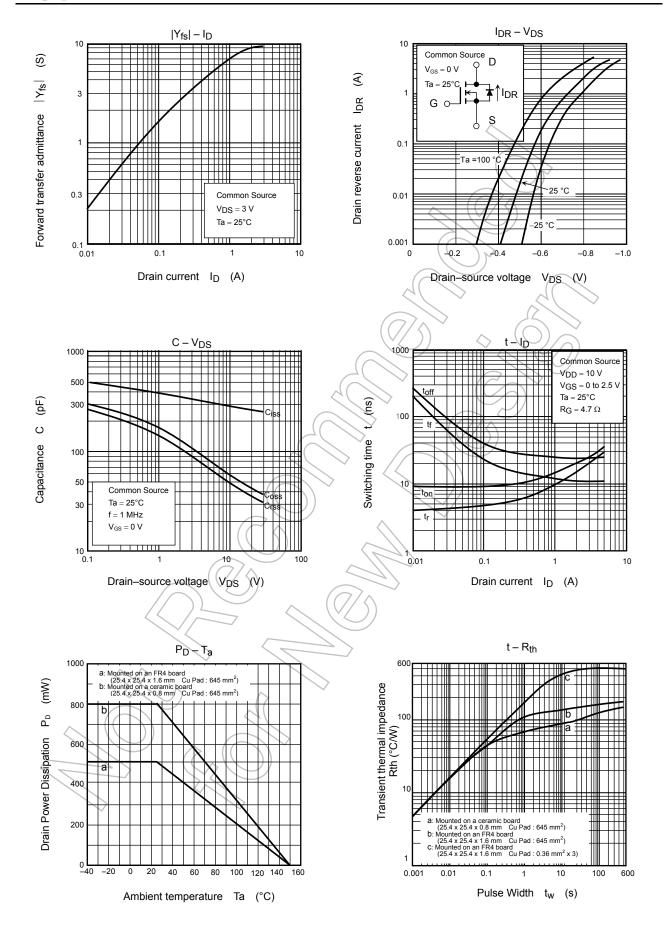
(The relationship can be established as follows: V<sub>GS</sub> (off) < V<sub>th</sub> < V<sub>GS</sub> (on).)

Take this into consideration when using the device.

#### **Handling Precaution**

When handling individual devices that are not yet mounted on a circuit board, make sure that the environment is protected against electrostatic discharge. Operators should wear antistatic clothing, and containers and other objects that come into direct contact with devices should be made of antistatic materials.





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